## Low Resistance, Low Distortion, RF Switching PIN Diode

## DESCRIPTION

The UM9701 PIN diode was designed for low resistance at low forward bias current and low reverse bias capacitance. This unique Microsemi design results in both forward and reverse bias.
These PIN diodes are characterized for low current drain RF and microwave switch applications particularly for digital filter switch designs. The construction and geometry of these devices provide good voltage and power handling capability.
These devices are constructed using a metallurgical full face bond to both

IMPORTANT: For the most current data, consult MICROSEMP's website: http://www.microsemi.com

| ABSOLUTE MAXIMUM RATINGS AT $25^{\circ} \mathrm{C}$ <br> (UNLESS OTHERWISE SPECIFIED) |  |  |  |
| :---: | :---: | :---: | :---: |
| Rating | Symbol | Value | Unit |
| Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | 100 | Volts |
| AVERAGE Power Dissipation <br> Free Air at 25 ${ }^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{A}}$ | 500 | mW |
| Average Power Dissipation <br> $1 / 2 "(12.7 \mathrm{~mm})$ Total lead Length <br> to $25^{\circ} \mathrm{C}$ Contacts | $\mathrm{P}_{\mathrm{A}}$ | 2.5 <br> Derate linearly <br> To $175^{\circ} \mathrm{C}$ | Watts |
| Storage Temperature | T stg | -65 to 175 | ${ }^{\circ} \mathrm{C}$ |
| Operating Temperature | T op | -65 to 175 | ${ }^{\circ} \mathrm{C}$ |

## ABSOLUTE MAXIMUM RATINGS AT $25^{\circ} \mathrm{C}$

 (UNLESS OTHERWISE SPECIFIED)
## KEY FEATURES

- Specified low distortion
- Low Forward Resistance
- High Reverse Resistance
- High Voltage Capability
- Good Power Handling
- Microsemi Ruggedness and reliability
- Compatible with automatic insertion equipment


## APPLICATIONS/BENEFITS

- Little or no Bias required.
- Available in leaded or surface mount packages.
- RoHS compliant packaging available: use UMX9701B, etc.


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## Electrical Specifications

| Test | Symbol | UM9701 | Conditions |
| :--- | :---: | :---: | :--- |
| Series Resistance (MAX) | $\mathrm{R}_{\mathrm{S}}$ | $0.8 \Omega$ | $\mathrm{~F}=100 \mathrm{MHz}, \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ |
| Total Capacitance (MAX) | $\mathrm{C}_{\mathrm{T}}$ | 1.8 pF | $\mathrm{F}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{R}}=50 \mathrm{~V}$ |
| Parallel Resistance (MIN) | $\mathrm{R}_{\mathrm{P}}$ | $100 \mathrm{k} \Omega$ | $\mathrm{F}=100 \mathrm{MHz}, \mathrm{V}_{\mathrm{R}}=50 \mathrm{~V}$ |
| Carrier Lifetime (MIN) | $\tau$ | $1.5 \mu \mathrm{~s}$ | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ |
| Reverse Current (MAX) | $\mathrm{I}_{\mathrm{R}}$ | $10 \mu \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{R}}=100 \mathrm{~V}$ |
| Forward Voltage (MAX) | $\mathrm{V}_{\mathrm{F}}$ | 0.8 V | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ |
| Forward Bias Third Order | R 2ab/a | -90 dB | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ <br> $\mathrm{P}_{\mathrm{A}}=\mathrm{P}_{\mathrm{B}}=+20 \mathrm{dBm}$ <br> $\mathrm{f}_{\mathrm{A}}=43 \mathrm{MHz}, \mathrm{f}_{\mathrm{B}}=44 \mathrm{MHz}$ |
| IM Distortion (MAX) | R 2ab/a | -90 dB | $\mathrm{V}_{\mathrm{R}}=50 \mathrm{~V}$ <br> $\mathrm{P}_{\mathrm{A}}=\mathrm{P}_{\mathrm{B}}=+20 \mathrm{dBm}$ <br> $\mathrm{f}_{\mathrm{A}}=43 \mathrm{MHz}, \mathrm{f}_{\mathrm{B}}=44 \mathrm{MHz}$ |
| Reverse Bias Third Order <br> IM Distortion (MAX) |  |  |  |

TYPICAL SERIES RESISTANCE VS FORWARD CURRENT


## Low Resistance, Low Distortion, RF Switching PIN Diode

TYPICAL DC CHARACTERISTIC


TYPICAL CAPACITANCE CHARACTERISTIC

typical parallel resistance vi reverse voltage


TYPICAL FORWARD BIAS INTERMODULATION DISTORTION
VERSUS NOMINAL CARRIER FREQUENCY


TYPICAL THIRD ORDER INTERMODULATION DISTORTION
(R 2ab/a) VERSUS FORWARD BIAS CURRENT


FORWARD BIAS THIRD ORDER INTERMODULATION DISTORTION (R 2ab/a) VS INPUT POWER PER CHANNEL


INPUT POWER PER CHANNEL (dBm)

TYPICAL REVERSE BIAS INTERMODULATION DISTORTION



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